

October 2015

# **FJN4301R PNP Epitaxial Silicon Transistor with Bias Resistor**

### **Features**

- 100 mA Output Current Capability
- Built-in Bias Resistor ( $R_1 = 4.7 \text{ k}\Omega$ ,  $R_2 = 4.7 \text{ k}\Omega$ )

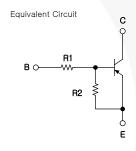
## **Applications**

- Switching, Interface, and Driver Circuits
- Inverters
- · Digital Applications in Industrial Segments



## Description

Transistors with built-in resistors can be excellent space- and cost-saving solutions by reducing component count and simplifying circuit design.



## **Ordering Information**

Part Number Top Mark		Package	Packing Method
FJN4301RTA	R4301	TO-92 3L	Ammo

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	-50	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-50	V
V <sub>EBO</sub>	Emitter-Base Voltage	-10	V
I <sub>C</sub>	Collector Current	-100	mA
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 to 150	°C

## Thermal Characteristics(1)

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Value	Unit
В	Power Dissipation	300	mW
P <sub>D</sub>	Derate Above T <sub>A</sub> = 25°C	2.4	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	416	°C/W

### Note:

## **Electrical Characteristics**

Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = -10  \mu A, I_E = 0$	-50			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = -100 \mu\text{A},  I_B = 0$	-50			V
I <sub>CBO</sub>	Collector Cut-Off Current	$V_{CB} = -40 \text{ V}, I_{E} = 0$			-0.1	μΑ
h <sub>FE</sub>	DC Current Gain	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	20			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$			-0.3	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$		200		MHz
C <sub>ob</sub>	Output Capacitance	$V_{CB} = -10 \text{ V}, I_{E} = 0,$ f = 1.0 MHz		5.5		pF
V <sub>I</sub> (off)	Input-Off Voltage	$V_{CE} = -5 \text{ V}, I_{C} = -100 \mu\text{A}$			-0.5	V
V <sub>I</sub> (on)	Input-On Voltage	$V_{CE} = -0.3 \text{ V}, I_{C} = -20 \text{ mA}$	-3			V
R <sub>1</sub>	Input Resistor		3.2	4.7	6.2	kΩ
R <sub>1</sub> /R <sub>2</sub>	Resistor Ratio		0.9	1.0	1.1	

<sup>1.</sup> PCB size: FR-4 76 x 114 x 0.6T mm<sup>3</sup> (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

## **Typical Performance Characteristics**

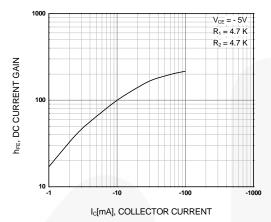


Figure 1. DC Current Gain

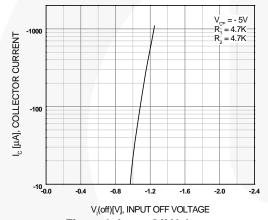


Figure 3. Input-Off Voltage

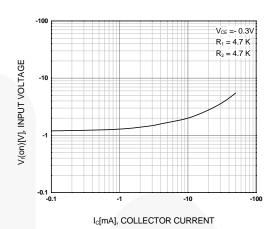


Figure 2. Input-On Voltage

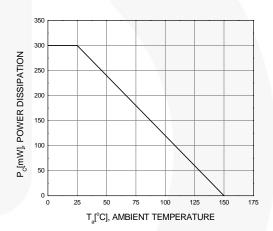
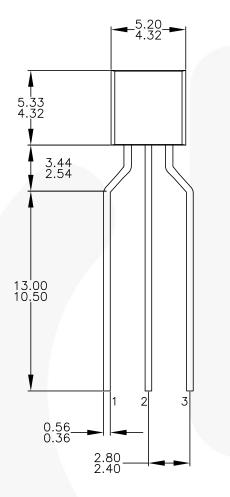
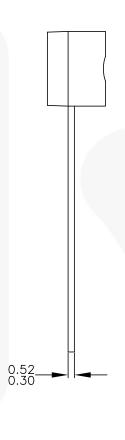
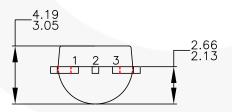


Figure 4. Power Derating

## **Physical Dimensions**







NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS—013, VARIATION AC.
  ALL DIMENSIONS ARE IN MILLIMETERS.
  DRAWING CONFORMS TO ASME Y14.5M—2009.
  DRAWING FILENAME: MKT—ZAO3FREV3.
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Figure 5. 3-LEAD, TO-92, MOLDED 0.200 IN-LINE SPACING LD FORM





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Definition of Terms			
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